

TECHNICAL DATA, PROVISIONAL DATA ONLY DATA SHEET 4117, Rev. C

HERMETIC SILICON CARBIDE RECTIFIER

DESCRIPTION: A 1200-VOLT, 5 AMP POWER SILICON CARBIDE RECTIFIER IN A CERAMIC HERMETIC SHD-1 HIGH PROFILE PACKAGE

FEATURES:

- NO RECOVERY TIME OR REVERSE RECOVERY LOSSES
- NO TEMPERATURE INFLUENCE ON SWITCHING BEHAVIOR

MAXIMUM RATINGS

ALL RATINGS ARE @ T_C = 25 °C UNLESS OTHERWISE SPECIFIED.

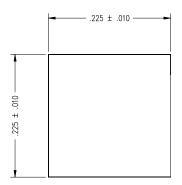
| MAXIMOM NATINGS ALE NATINGS AIL & 10-25 C | ONLEGO OTTIL | INVIOL OF LOT | ILD. |
|---|------------------|----------------|-------|
| RATING | SYMBOL | MAX. | UNITS |
| PEAK INVERSE VOLTAGE | PIV | 1200 | Volts |
| MAXIMUM DC OUTPUT CURRENT | Io | 5 | Amps |
| MAXIMUM REPETITIVE FORWARD SURGE CURRENT (t = 8.3ms, Sine) | I _{FRM} | 30 | Amps |
| MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT $(t = 10\mu s, pulse)$ | I _{FSM} | 100 | Amps |
| MAXIMUM JUNCTION CAPACITANCE (V _r =5V) | C _T | 450 | pF |
| MAXIMUM POWER DISSIPATION | P _d | 15 | W |
| MAXIMUM THERMAL RESISTANCE (Junction to Case) | $R_{	heta JC}$ | 2.40 | °C/W |
| MAXIMUM OPERATING AND STORAGE TEMPERATURE RANGE | Top, Tstg | -55 to +200 | °C |

ELECTRICAL CHARACTERISTICS

| CHARACTERISTIC | TYP | MAX. | UNITS |
|--|------|------|-------|
| MAXIMUM FORWARD VOLTAGE DROP I _f = 5 A, T _J =25 °C | 1.65 | 1.80 | |
| T _J =175 °C | 2.55 | 3.00 | Volts |
| MAXIMUM REVERSE CURRENT PIV = 1200V, T _J = 25 °C | 0.05 | 0.40 | |
| T _J = 175 °C | 0.10 | 2.00 | mA |
| TOTAL CAPACITIVE CHARGE (V _R =1200V, I _F =5A, di/dt=500A/ μ s and T _J =25°C) Q _C | 28 | N/A | nC |

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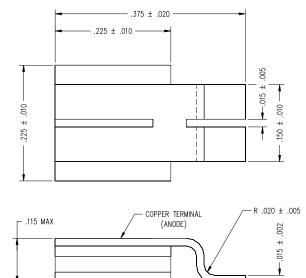
MECHANICAL DIMENSIONS: In Inches / mm



SHD-1 HP



SHD-1B HP



.060 ± .010

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Figure 1. Forward Characteristics

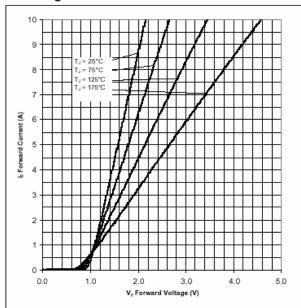
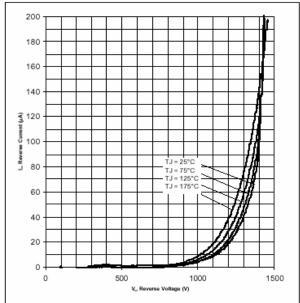


Figure 2. Reverse Characteristics



Application Note: Customers should be aware that at the current stage of technical development of SiC, the reverse avalanche capabilities of the device are limited.

Customer designs will need to accommodate these limitations and avoid exposure of the device to this and other potentially damaging conditions in their applications.

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